NSN 5980-01-354-7282

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nclosure Material:
Metal
Overall Length:
Between 0.500 inches and 0.520 inches
Overall Diameter:
Between 0.373 inches and 0.388 inches
Mounting Facility Quantity:
1
nternal Configuration:
Point contact
nternal Junction Configuration:
Pn
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and mounting hardware
Thread Size:
0.312 inches
Semiconductor Material:
Gallium phosphide
Voltage Rating In Volts Per Characteristic:
5.0 breakdown voltage, dc
Current Rating Per Characteristic:
35.00 milliamperes source cutoff current preset
Color Tone Produced Per Source:
Red semiconductor
Luminous Intensity:
20.0 millicandela
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Test Data Document:
31349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Jnef
Terminal Type And Quantity:
2 pin
Specification Data:
31349-mil-s-19500/519 government specification
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.